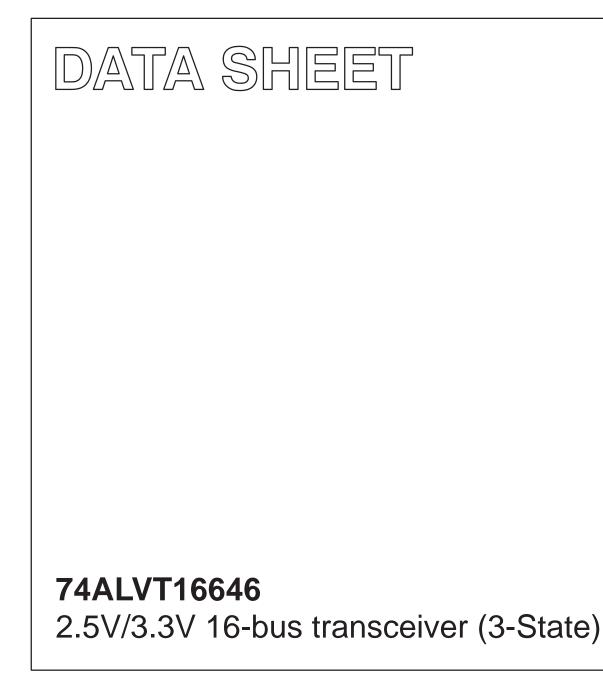
INTEGRATED CIRCUITS



Product specification Supersedes data of 1996 Aug 13 IC23 Data Handbook

1998 Feb 13



Philips Semiconductors

74ALVT16646

FEATURES

- 16-bit universal bus interface
- 5V I/O Compatible
- 3-State buffers
- Output capability: +64mA/-32mA
- TTL input and output switching levels
- Input and output interface capability to systems at 5V supply
- Bus-hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Live insertion/extraction permitted
- No bus current loading when output is tied to 5V bus
- Power-up reset
- Power-up 3-State
- Latch-up protection exceeds 500mA per JEDEC Std 17
- ESD protection exceeds 2000V per MIL STD 883 Method 3015 and 200V per Machine Model

QUICK REFERENCE DATA

DESCRIPTION

The 74ALVT16646 is a high-performance BiCMOS product designed for V_{CC} operation at 2.5V or 3.3V with I/O compatibility up to 5V.

This device is a 16-bit transceiver featuring non-inverting 3-State bus compatible outputs in both send and receive directions. The control function implementation minimizes external timing requirements. The device features an Output Enable (\overline{OE}) input for easy cascading and a Direction (DIR) input for direction control.

Data on the A or B bus is clocked into the registers on the Low to High transition of the appropriate clock (CPAB or CPBA). The select-control (SAB and SBA) inputs can multiplex stored and real-time (transparent mode data).

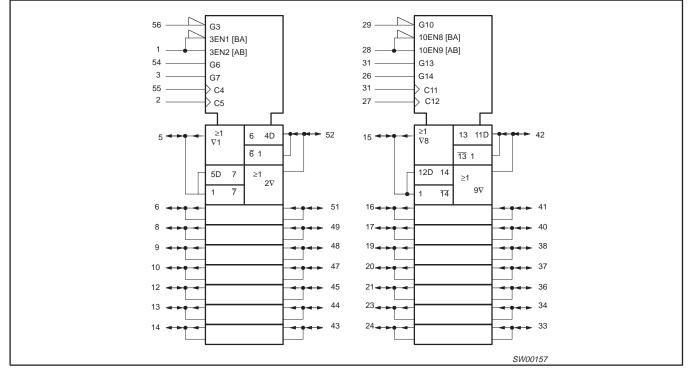
SYMBOL	PARAMETER	CONDITIONS	TYPI	UNIT	
STMBOL		T _{amb} = 25°C	2.5V	3.3V	UNIT
t _{PLH} t _{PHL}	Propagation delay nAx to nBx or nBx to nAx	C _L = 50pF	2.2 2.3	1.7 1.8	ns
C _{IN}	Input capacitance DIR, OE	$V_{I} = 0V \text{ or } V_{CC}$	3	3	pF
C _{I/O}	I/O pin capacitance	$V_{I/O} = 0V \text{ or } V_{CC}$	9	9	pF
I _{CCZ}	Total supply current	Outputs disabled	40	70	μΑ

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
56-Pin Plastic SSOP Type III	–40°C to +85°C	74ALVT166646 DL	AV16646 DL	SOT371-1
56-Pin Plastic TSSOP Type II	–40°C to +85°C	74ALVT16646 DGG	AV16646 DGG	SOT364-1

74ALVT16646

LOGIC SYMBOL (IEEE/IEC)

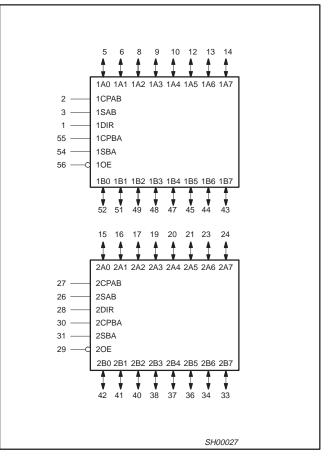


74ALVT16646

_			
		56	1 0E
1CPAB	2	55	1CPBA
1SAB	3	54	1SBA
GND	4	53	GND
1A0	5	52	1B0
1A1	6	51	1B1
Vcc	7	50	VCC
1A2	8	49	1B2
1A3	9	48	1B3
1A4 1	10	47	1B4
GND [11	46	GND
1A5 [1	12	45	1B5
1A6 1	13	44	1B6
1A7 1	14	43	1B7
2A0 1	15	42	2B0
2A1 [16	41	2B1
2A2 1	17	40	2B2
GND 1	18	39	GND
2A3 1	19	38	2B3
2A4 2	20	37	2B4
2A5	21	36	2B5
V _{CC}	22	35	V _{CC}
2A6	23	34	2B6
2A7	24	33	2B7
GND 2	25	32	GND
2SAB	26	31	2SBA
2CPAB	27	30	2CPBA
2DIR	28	29	20E
	SH000)26	

PIN CONFIGURATION

LOGIC SYMBOL

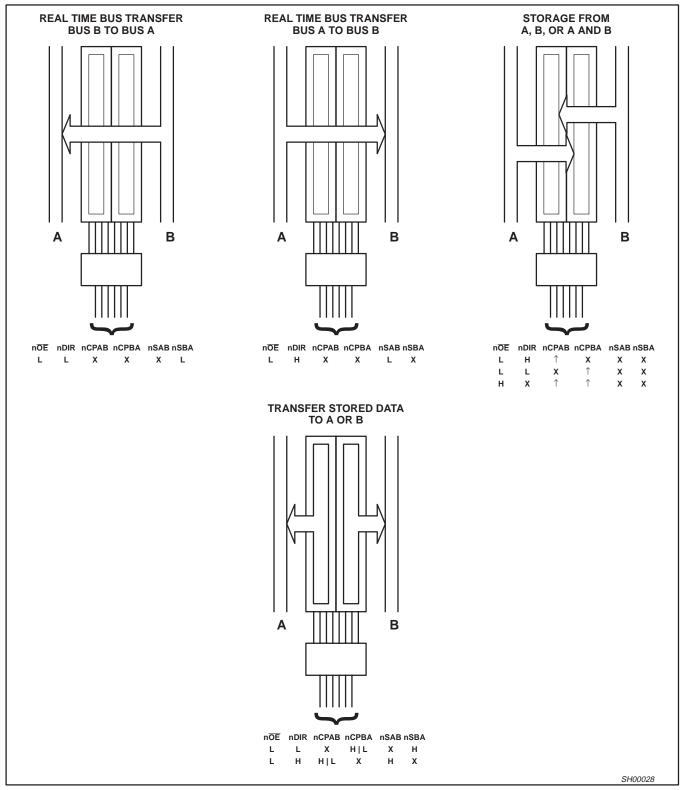


PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
2, 55, 27, 30	1CPAB, 1CPBA, 2CPAB, 2CPBA	Clock input A to B / Clock input B to A
3, 54, 26, 31	1SAB, 1SBA, 2SAB, 2SBA	Select input A to B / Select input B to A
1, 28	1DIR, 2DIR	Direction control inputs
5, 6, 8, 9, 10, 12, 13, 14 15, 16, 17, 19, 20, 21, 23, 24	1A0 - 1A7, 2A0 - 2A7	Data inputs/outputs (A side)
52, 51, 49, 48, 47, 45, 44, 43 42, 41, 40, 38, 37, 36, 34, 33	1B0 - 1B7, 2B0 - 2B7	Data inputs/outputs (B side)
56, 29	10E, 20E	Output enable inputs
4, 11, 18, 25, 32, 39, 46, 53	GND	Ground (0V)
7, 22, 35, 50	V _{CC}	Positive supply voltage

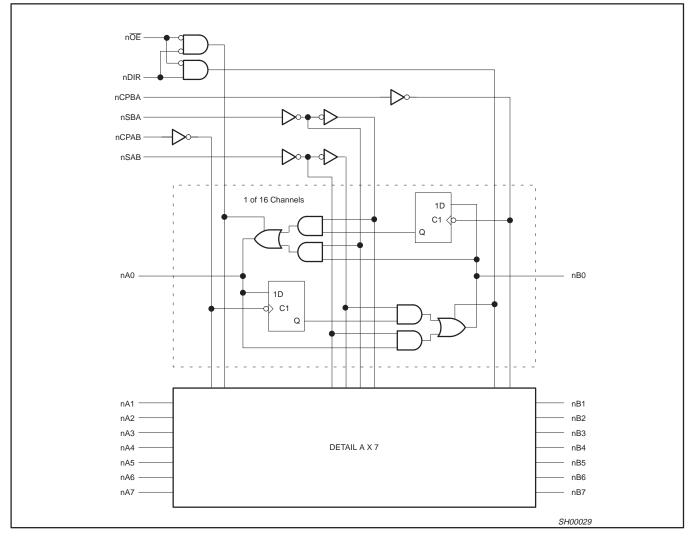
74ALVT16646

The following examples demonstrate the four fundamental bus-management functions that can be performed with the 74ALVT16646.



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LOGIC DIAGRAM



FUNCTION TABLE

		INPUTS	3			DAT	A I/O	OPERATING MODE
nOE	nDIR	nCPAB	nCPBA	nSAB	nSBA	nAx	nBx	OPERATING MODE
х	Х	ſ	Х	х	Х	Input	Unspecified output*	Store A, B unspecified
х	Х	Х	\uparrow	х	Х	Unspecified output*	Input	Store B, A unspecified
H H	X X	↑ H or L	↑ H or L	X X	X X	Input	Input	Store A and B data Isolation, hold storage
L	L L	X X	X H or L	X X	L H	Output	Input	Real time B data to A bus Stored B data to A bus
L L	H H	X H or L	X X	L H	X X	Input	Output	Real time A data to B bus Stored A data to B bus

H = High voltage level

Low voltage level L =

= Don't care

X ↑ = Low-to-High clock transition

The data output function may be enabled or disabled by various signals at the nOE input. Data input functions are always enabled, i.e., data at the bus pins will be stored on every Low-to-High transition of the clock.

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ABSOLUTE MAXIMUM RATINGS^{1, 2}

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +4.6	V
I _{IK}	DC input diode current	V ₁ < 0	-50	mA
VI	DC input voltage ³		-0.5 to +7.0	V
I _{OK}	DC output diode current	V _O < 0	-50	mA
V _{OUT}	DC output voltage ³	Output in Off or High state	-0.5 to +7.0	V
1	DC output current	Output in Low state	128	mA
lout		Output in High state	-64	1
T _{stg}	Storage temperature range		-65 to +150	°C

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

 The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.

3. The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	2.5V RAN	GE LIMITS	3.3V RAN	UNIT	
STMBOL	FARAMETER	MIN	MAX	MIN	MAX	UNIT
V _{CC}	DC supply voltage	2.3	2.7	3.0	3.6	V
VI	Input voltage	0	5.5	0	5.5	V
V _{IH}	High-level input voltage	1.7		2.0		V
V _{IL}	Input voltage		0.7		0.8	V
I _{OH}	High-level output current		-8		-32	mA
le:	Low-level output current		8		32	mA
IOL	Low-level output current; current duty cycle \leq 50%; f \geq 1kHz		24		64	IIIA
$\Delta t/\Delta v$	Input transition rise or fall rate; Outputs enabled		10		10	ns/V
T _{amb}	Operating free-air temperature range	-40	+85	-40	+85	°C

74ALVT16646

DC ELECTRICAL CHARACTERISTICS (3.3V ±0.3V RANGE)

					LIMITS		
SYMBOL	PARAMETER	TEST CONDITIONS		Temp = -40°C to		+85°C	тил Т
					TYP ¹	MAX	1
V _{IK}	Input clamp voltage	$V_{CC} = 3.0V; I_{IK} = -18mA$			-0.85	-1.2	V
Maria	High-level output voltage	V _{CC} = 3.0 to 3.6V; I _{OH} = -100µA		V _{CC} -0.2	V _{CC}		v
V _{OH}	nigh-level output voltage	V _{CC} = 3.0V; I _{OH} = -32mA		2.0	2.3		
		V _{CC} = 3.0V; I _{OL} = 100µA			0.07	0.2	
V _{OL}	Low-level output voltage	V _{CC} = 3.0V; I _{OL} = 16mA	V _{CC} = 3.0V; I _{OL} = 16mA		0.25	0.4	V
		V _{CC} = 3.0V; I _{OL} = 32mA			0.3	0.5	
		V _{CC} = 3.0V; I _{OL} = 64mA			0.4	0.55	
V _{RST}	Power-up output low voltage ⁶	V_{CC} = 3.6V; I _O = 1mA; V _I = V _{CC} or GND				0.55	V
		V_{CC} = 3.6V; V_{I} = V_{CC} or GND	Control pins		0.1	±1	μΑ
		$V_{CC} = 0 \text{ or } 3.6 \text{V}; \text{ V}_{\text{I}} = 5.5 \text{V}$	Control pins		0.1	10	
I _I	Input leakage current	$V_{CC} = 3.6V; V_1 = 5.5V$			0.1	20	
		$V_{CC} = 3.6V; V_1 = V_{CC}$	I/O Data pins ⁴		0.5	10	
		$V_{CC} = 3.6V; V_1 = 0$	1		0.1	-5	
I _{OFF}	Off current	$V_{CC} = 0V; V_1 \text{ or } V_O = 0 \text{ to } 4.5V$			0.1	±100	μΑ
	Bus Hold current	$V_{CC} = 3V; V_{I} = 0.8V$		75	130		μΑ
I _{HOLD}	Data inputs ⁷	$V_{CC} = 3V; V_1 = 2.0V$		-75	-140		μΑ
		$V_{CC} = 3.0V; V_{I} = 0V \text{ to } 3.6V$		±500			μA
I_{EX}	Current into an output in the High state when $V_O > V_{CC}$	V _O = 5.5V; V _{CC} = 3.0V			50	125	μA
I _{PU/PD}	Power up/down 3-State output current ³	$V_{CC} \leq$ 1.2V; V_O = 0.5V to $V_{CC};$ V_I = GNE OE/OE = Don't care) or V _{CC} ;		40	±100	μA
I _{CCH}		V_{CC} = 3.6V; Outputs High, V_{I} = GND or $V_{CC,\ I_{O}}$ = 0			0.07	0.14	
I _{CCL}	Quiescent supply current	V_{CC} = 3.6V; Outputs Low, V_{I} = GND or V_{CC} , I_{O} = 0			3.2	7	mA
I _{CCZ}	1	V_{CC} = 3.6V; Outputs Disabled; V_{I} = GND	0 or V_{CC} , $I_{O} = 0^5$		0.07	0.14	
ΔI_{CC}	Additional supply current per input pin ²	V_{CC} = 3V to 3.6V; One input at V _{CC} -0.6 Other inputs at V _{CC} or GND	V,		0.04	0.4	mA

NOTES:

All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.
This is the increase in supply current for each input at the specified voltage level other than V_{CC} or GND
This parameter is valid for any V_{CC} between 0V and 1.2V with a transition time of up to 10msec. From V_{CC} = 1.2V to V_{CC} = 3.3V ± 0.3V a transition time of 100µsec is permitted. This parameter is valid for T_{amb} = 25°C only.
Unused pins at V_{CC} or GND.

5. I_{CCZ} is measured with outputs pulled up to V_{CC} or pulled down to ground. 6. For valid test results, data must not be loaded into the flip-flops (or latches) after applying power.

7. This is the bus hold overdrive current required to force the input to the opposite logic state.

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AC CHARACTERISTICS (3.3V ±0.3V RANGE)

GND = 0V; $t_R = t_F = 2.5ns$; $C_L = 50pF$; $R_L = 500\Omega$; $T_{amb} = -40^{\circ}C$ to +85°C.

				LIMITS				
SYMBOL	PARAMETER	WAVEFORM	Vc	UNIT				
			MIN	TYP ¹	MAX	1		
f _{MAX}	Maximum clock frequency	1	150			MHz		
t _{PLH} t _{PHL}	Propagation delay nCPAB to nBx or nCPBA to nAx	1	1.0 1.0	2.6 2.1	3.7 3.1	ns		
t _{PLH} t _{PHL}	Propagation delay nSAB to nBx or nSBA to nAx	2	1.0 1.0	2.4 2.1	4.0 3.8	ns		
t _{PLH} t _{PHL}	Propagation delay nAx to nBx or nBx to nAx	2 3	0.5 0.5	1.7 1.8	2.4 2.8	ns		
t _{PZH} t _{PZL}	Output enable time to High and Low level	5 6	0.5 0.5	2.3 2.0	3.9 4.4	ns		
t _{PHZ} t _{PLZ}	Output disable time from High and Low Level	5 6	1.5 1.5	3.4 2.8	5.0 4.2	ns		
t _{PZH} t _{PZL}	Output enable time nDIR to nAx or nBx	5 6	1.0 0.5	2.8 2.2	5.0 4.7	ns		
t _{PHZ} t _{PLZ}	Output disable time nDIR to nAx or nBx	5 6	1.5 1.0	3.5 3.1	5.4 4.7	ns		

NOTE:

1. All typical values are at V_{CC} = 3.3V and T_{amb} = 25° C.

AC SETUP REQUIREMENTS (3.3V \pm 0.3V RANGE)

GND = 0V; $t_R = t_F = 2.5ns$; $C_L = 50pF$; $R_L = 500\Omega$; $T_{amb} = -40^{\circ}C$ to +85°C.

			LIMITS		
SYMBOL	PARAMETER	WAVEFORM	V _{CC} = 3.3	$3V \pm 0.3V$	UNIT
			MIN	TYP ¹	
t _S (H) t _S (L)	Setup time, High or Low nAx to nCPAB or nBx to nCPBA	4	1.6 1.6	1.0 1.0	ns
t _h (H) t _h (L)	Hold time, High or Low nAx to nCPAB or nBx or nCPBA	4	0.0 0.0	-0.5 -0.7	ns
t _w (H) t _w (L)	Pulse width, High or Low nCPAB or nCPBA	1	1.5 1.5		ns

NOTE:

1. This data sheet limit may vary among suppliers.

74ALVT16646

DC ELECTRICAL CHARACTERISTICS (2.5V \pm 0.2V RANGE)

					LIMITS		
SYMBOL	PARAMETER	TEST CONDITIONS		Temp = -40°C t		+85°C	UNIT
			MIN	TYP ¹	MAX		
VIK	Input clamp voltage	$V_{CC} = 2.3V; I_{IK} = -18mA$			-0.85	-1.2	V
V _{OH}	High-level output voltage	$V_{CC} = 2.3$ to 3.6V; $I_{OH} = -100\mu A$		V _{CC} -0.2	V _{CC}		V
VOH	nigh-level output voltage	V _{CC} = 2.3V; I _{OH} = -8mA		1.8	2.1		Ň
		V _{CC} = 2.3V; I _{OL} = 100µA			0.07	0.2	
V _{OL}	Low-level output voltage	V _{CC} = 2.3V; I _{OL} = 24mA			0.3	0.5	V
		$V_{CC} = 2.3V; I_{OL} = 8mA$				0.4	
V _{RST}	Power-up output low voltage ⁷	V_{CC} = 2.7V; I_{O} = 1mA; V_{I} = V_{CC} or GND				0.55	V
		$V_{CC} = 2.7V; V_I = V_{CC} \text{ or } GND$	Control pins		0.1	±1	
		$V_{CC} = 0 \text{ or } 2.7 \text{V}; \text{ V}_{\text{I}} = 5.5 \text{V}$	Control pins		0.1	10	μA
I	Input leakage current	$V_{CC} = 2.7 V; V_{I} = 5.5 V$			0.1	20	
		$V_{CC} = 2.7V; V_{I} = V_{CC}$	I/O Data pins ⁴		0.1	10	1
		$V_{CC} = 2.7V; V_I = 0$			0.1	-5	1
I _{OFF}	Off current	$V_{CC} = 0V; V_{I} \text{ or } V_{O} = 0 \text{ to } 4.5V$			0.1	±100	μΑ
I _{HOLD}	Bus Hold current	$V_{CC} = 2.3V; V_I = 0.7V$			90		μΑ
	A or B inputs ⁶	V _{CC} = 2.3V; V _I = 1.7V			-10		μA
I _{EX}	Current into an output in the High state when $V_O > V_{CC}$	V _O = 5.5V; V _{CC} = 2.3V			50	125	μA
I _{PU/PD}	Power up/down 3-State output current ³	$V_{CC} \le 1.2$ V; $V_O = 0.5$ V to V_{CC} ; $V_I = GNE OE/OE = Don't care$) or V _{CC} ;		40	100	μΑ
I _{CCH}		V_{CC} = 2.7V; Outputs High, V_{I} = GND or V	V _{CC} , I _{O =} 0		0.04	0.1	
I _{CCL}	Quiescent supply current	$V_{CC} = 2.7V$; Outputs Low, $V_I = GND$ or V_{CC} , $I_O = 0$			2.3	4.5	mA
I _{CCZ}	1	V_{CC} = 2.7V; Outputs Disabled; V_{I} = GND) or $V_{CC, I_{O}} = 0^5$		0.04	0.1	
ΔI_{CC}	Additional supply current per input pin ²	V_{CC} = 2.3V to 2.7V; One input at V_{CC} -0. Other inputs at V_{CC} or GND	6V,		0.01	0.4	mA

NOTES:

All typical values are at V_{CC} = 2.5V and T_{amb} = 25°C.
This is the increase in supply current for each input at the specified voltage level other than V_{CC} or GND
This parameter is valid for any V_{CC} between 0V and 1.2V with a transition time of up to 10msec. From V_{CC} = 1.2V to V_{CC} = 2.5V ± 0.2V a transition time of 100µsec is permitted. This parameter is valid for T_{amb} = 25°C only.
Unused pins at V_{CC} or GND.
I_{CCZ} is measured with outputs pulled up to V_{CC} or pulled down to ground.
Not guaranteed.
For valid test results, data must not be loaded into the flip flops (or latches) after applying power.

7. For valid test results, data must not be loaded into the flip-flops (or latches) after applying power.

74ALVT16646

AC CHARACTERISTICS (2.5V ±0.2V RANGE)

GND = 0V; $t_R = t_F = 2.5ns$; $C_L = 50pF$; $R_L = 500\Omega$; $T_{amb} = -40^{\circ}C$ to +85°C.

				LIMITS V _{CC} = 2.5V ±0.2V			
SYMBOL	PARAMETER	WAVEFORM	Vc				
			MIN	TYP ¹	MAX	1	
f _{MAX}	Maximum clock frequency	1	150			MHz	
t _{PLH} t _{PHL}	Propagation delay nCPAB to nBx or nCPBA to nAx	1	1.0 1.0	3.2 2.8	4.8 4.2	ns	
t _{PLH} t _{PHL}	Propagation delay nSAB to nBx or nSBA to nAx	2	1.5 1.5	3.4 3.4	5.8 6.0	ns	
t _{PLH} t _{PHL}	Propagation delay nAx to nBx or nBx to nAx	2 3	0.5 0.5	2.2 2.3	3.2 3.8	ns	
t _{PZH} t _{PZL}	Output enable time to High and Low level	5 6	1.5 1.0	3.4 2.7	5.8 6.0	ns	
t _{PHZ} t _{PLZ}	Output disable time from High and Low Level	5 6	1.5 1.0	3.2 2.5	5.2 3.7	ns	
t _{PZH} t _{PZL}	Output enable time nDIR to nAx or nBx	5 6	2.0 1.0	4.1 2.5	7.0 4.1	ns	
t _{PHZ} t _{PLZ}	Output disable time nDIR to nAx or nBx	5 6	1.5 1.0	3.9 3.1	6.1 4.9	ns	

NOTE:

1. All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.

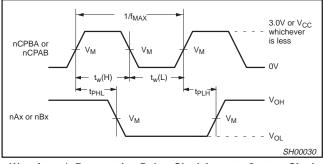
AC SETUP REQUIREMENTS (2.5V \pm 0.2V RANGE)

GND = 0V; $t_R = t_F = 2.5ns$; $C_L = 50pF$; $R_L = 500\Omega$; $T_{amb} = -40^{\circ}C$ to $+85^{\circ}C$.

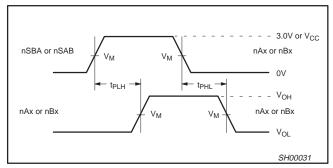
			LIMITS			
SYMBOL	PARAMETER	WAVEFORM	V _{CC} = 2.5	5V ±0.2V	UNIT	
			MIN	ТҮР		
t _S (H) t _S (L)	Setup time, High or Low nAx to nCPAB or nBx to nCPBA	4	2.0 2.0	1.2 1.2	ns	
t _h (H) t _h (L)	Hold time, High or Low 4 nAx to nCPAB or nBx or nCPBA		0.0 0.0	-1.0 -1.0	ns	
t _w (H) t _w (L)	Pulse width, High or Low nCPAB or nCPBA	1	1.5 1.5		ns	

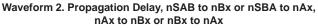
AC WAVEFORMS

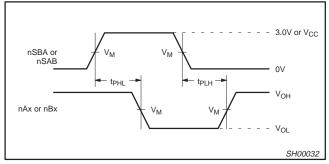
 $\begin{array}{l} \mathsf{V}_{\mathsf{M}} = 1.5\mathsf{V} \text{ at } \mathsf{V}_{\mathsf{CC}} \geq 3.0\mathsf{V}; \ \mathsf{V}_{\mathsf{M}} = \mathsf{V}_{\mathsf{CC}}/2 \text{ at } \mathsf{V}_{\mathsf{CC}} \leq 2.7\mathsf{V} \\ \mathsf{V}_{\mathsf{X}} = \mathsf{V}_{\mathsf{OL}} + 0.3\mathsf{V} \text{ at } \mathsf{V}_{\mathsf{CC}} \geq 3.0\mathsf{V}; \ \mathsf{V}_{\mathsf{X}} = \mathsf{V}_{\mathsf{OL}} + 0.15\mathsf{V} \text{ at } \mathsf{V}_{\mathsf{CC}} \leq 2.7\mathsf{V} \\ \mathsf{V}_{\mathsf{Y}} = \mathsf{V}_{\mathsf{OH}} - 0.3\mathsf{V} \text{ at } \mathsf{V}_{\mathsf{CC}} \geq 3.0\mathsf{V}; \ \mathsf{V}_{\mathsf{Y}} = \mathsf{V}_{\mathsf{OH}} - 0.15\mathsf{V} \text{ at } \mathsf{V}_{\mathsf{CC}} \leq 2.7\mathsf{V} \\ \end{array}$



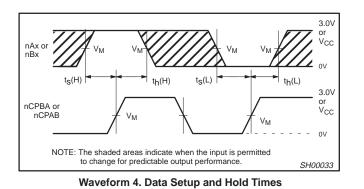
Waveform 1. Propagation Delay, Clock Input to Output, Clock Pulse Width, and Maximum Clock Frequency



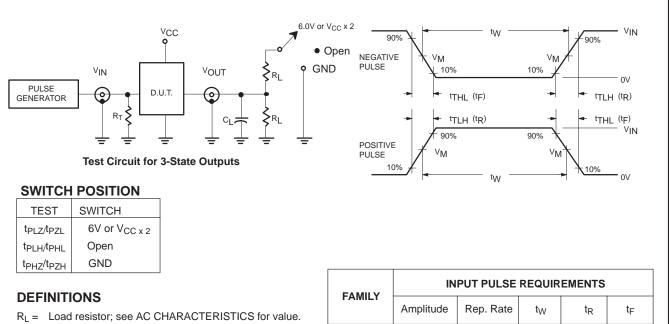




Waveform 3. Propagation Delay, nSBA to nAx or nSAB to nBx



TEST CIRCUIT AND WAVEFORMS



74ALVT16

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- C_{I} = Load capacitance includes jig and probe capacitance: See AC CHARACTERISTICS for value.
- Termination resistance should be equal to ZOUT of $R_T =$ pulse generators.

FAMILY	IN	PUT PULSE	REQUIR	EMENTS	

500ns

≤2.5ns

≤2.5ns

SW00025

 $\leq 10 MHz$

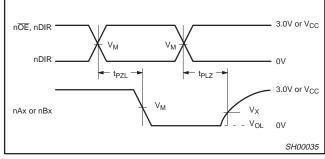
3.0V or V_{CC}

whichever

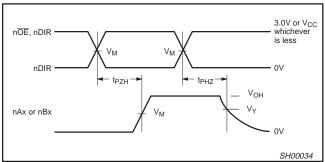
is less

V_{OH} V_v nAx or nBx Vм 0 SH00034

Waveform 5. 3-State Output Enable Time to High Level and **Output Disable Time from High Level**



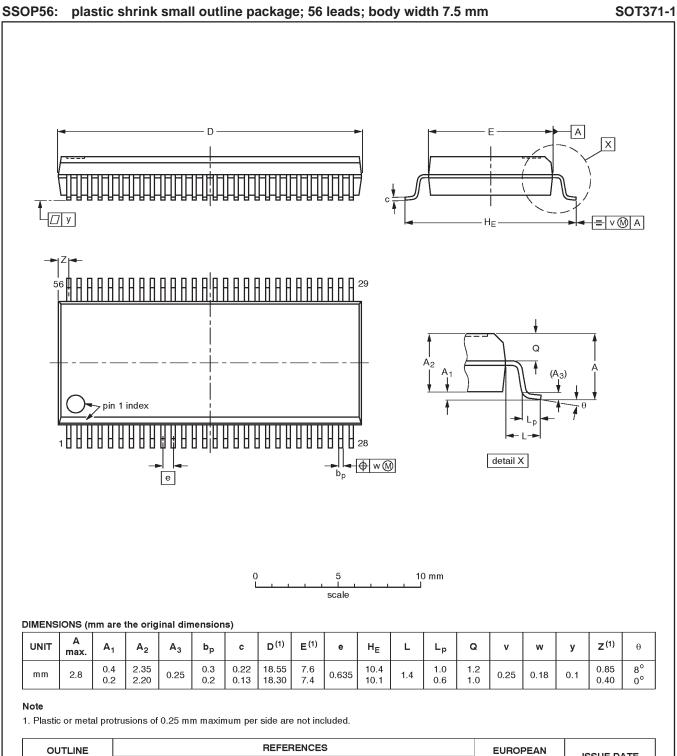
Waveform 6. 3-State Output Enable Time to Low Level and **Output Disable Time from Low Level**



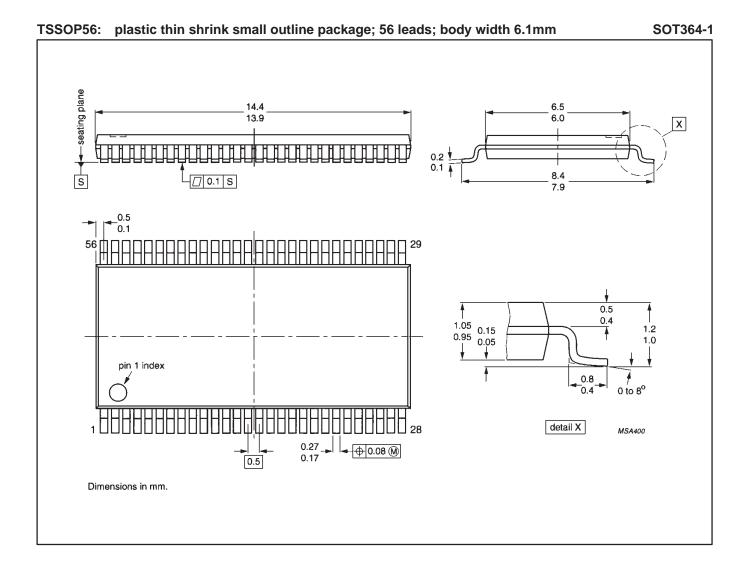


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Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
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